

radiation-induced defects. This reduction in phonon scattering was a strong indication that the main phonon scattering was from mobile dislocations, rather than from their static strain fields. To further test these ideas, we γ irradiated our dislocated sample with a Cs source and then compared the intensities of horizontal and vertical FTA ridges. With 0.6 Mrad of γ radiation the scattering strength β was found to decrease by a factor of 7, shown as the dotted line in Fig. 3(c). With a 6-Mrad dose, the intensity of the vertical ridge was increased by an additional factor of 7, as shown by the dashed line in Fig. 3(c). Thus we find that the γ irradiation reduced the total scattering strength by nearly a factor of 50. This large reduction in scattering of particular phonon polarizations with irradiation may be contrasted to the much smaller reduction in thermal conductivity, where many modes and polarizations are sampled.

Our experiments and analyses thus show that the method of ballistic phonon imaging yields new and interesting details about the scattering of high-frequency phonons from dislocations in LiF. The ability to quantitatively sample the phonon transmission as a continuous function of propagation angle and accurately identify the phonon polarization from the singularity pattern provides a powerful new approach to characterizing the interaction of phonons with defects in insulators.

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GERD BINNIG & HEINRICH ROHRER

sont les auteurs de l'article. En 1986, ils sont récompensés par Le Prix Nobel de physique pour leur découverte.

SURFACE STUDIES BY SCANNING TUNNELING MICROSCOPY

Surface Studies by Scanning Tunneling Microscopy

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Surface microscopy using vacuum tunneling is demonstrated for the first time. Topographic pictures of surfaces on an atomic scale have been obtained. Examples of resolved monoatomic steps and surface reconstructions are shown for (110) surfaces of CaIrSn_4 and Au.

PACS numbers: 68.20.+1, 73.40.Gk

In two previous reports,^{1,2} we demonstrated the experimental feasibility of controlled vacuum tunneling. The tunnel current flowed from a W tip to a Pt surface at some 10 Å distance from each other. The tunnel distance could be stabilized within 0.2 Å. These experiments were the first step towards the development of scanning tunneling microscopy. Previous developments were unsuccessful for various reasons.³

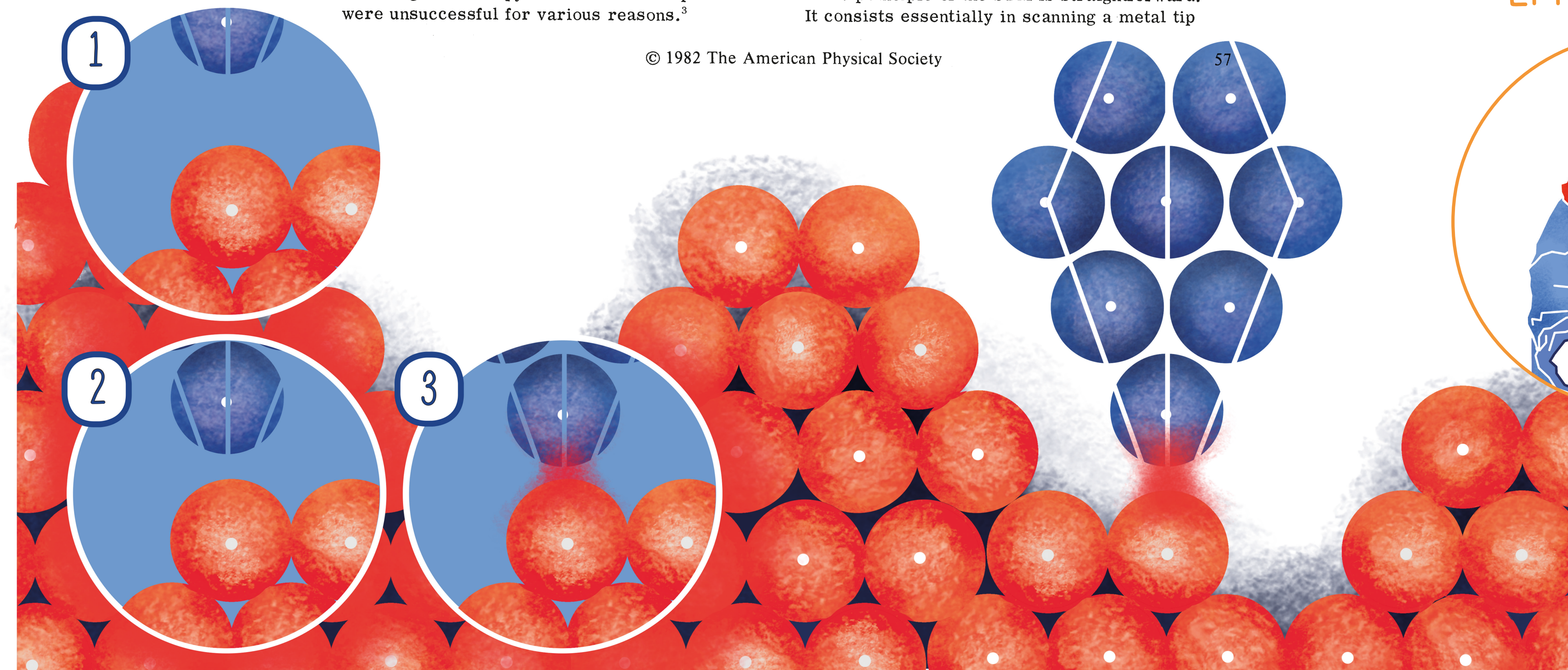
The present Letter contains the first experimental results on surface topography obtained with this novel technique. They demonstrate an unprecedented resolution of the scanning tunneling microscope (STM) and should give a taste of its fascinating possibilities for surface characterization.

The principle of the STM is straightforward. It consists essentially in scanning a metal tip

EFFET TUNNEL



Dans ce microscope, on approche une pointe très près de la surface. Quand elle est au dessus d'un atome, on détecte un courant électrique qui apparaît par effet tunnel.

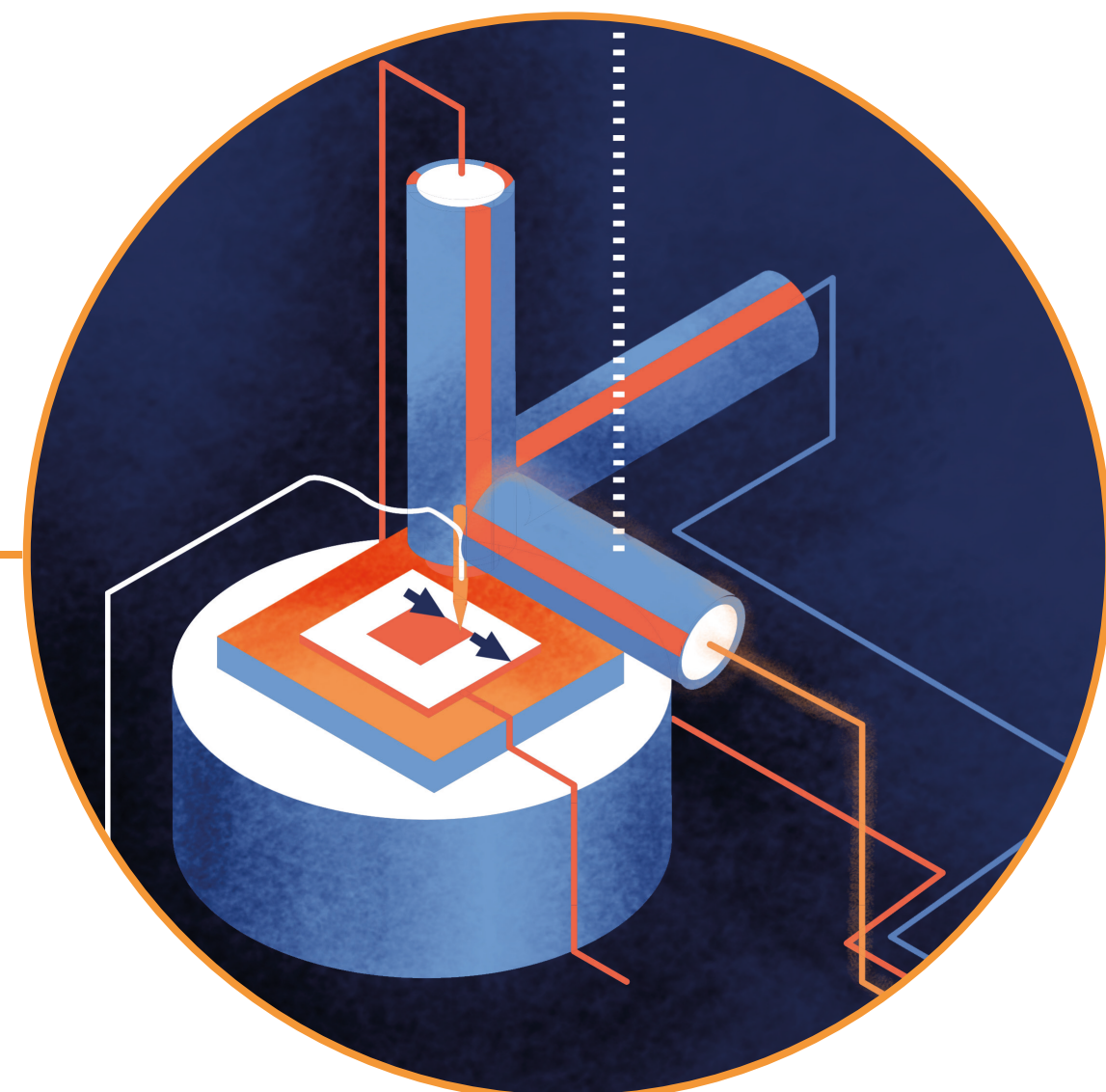
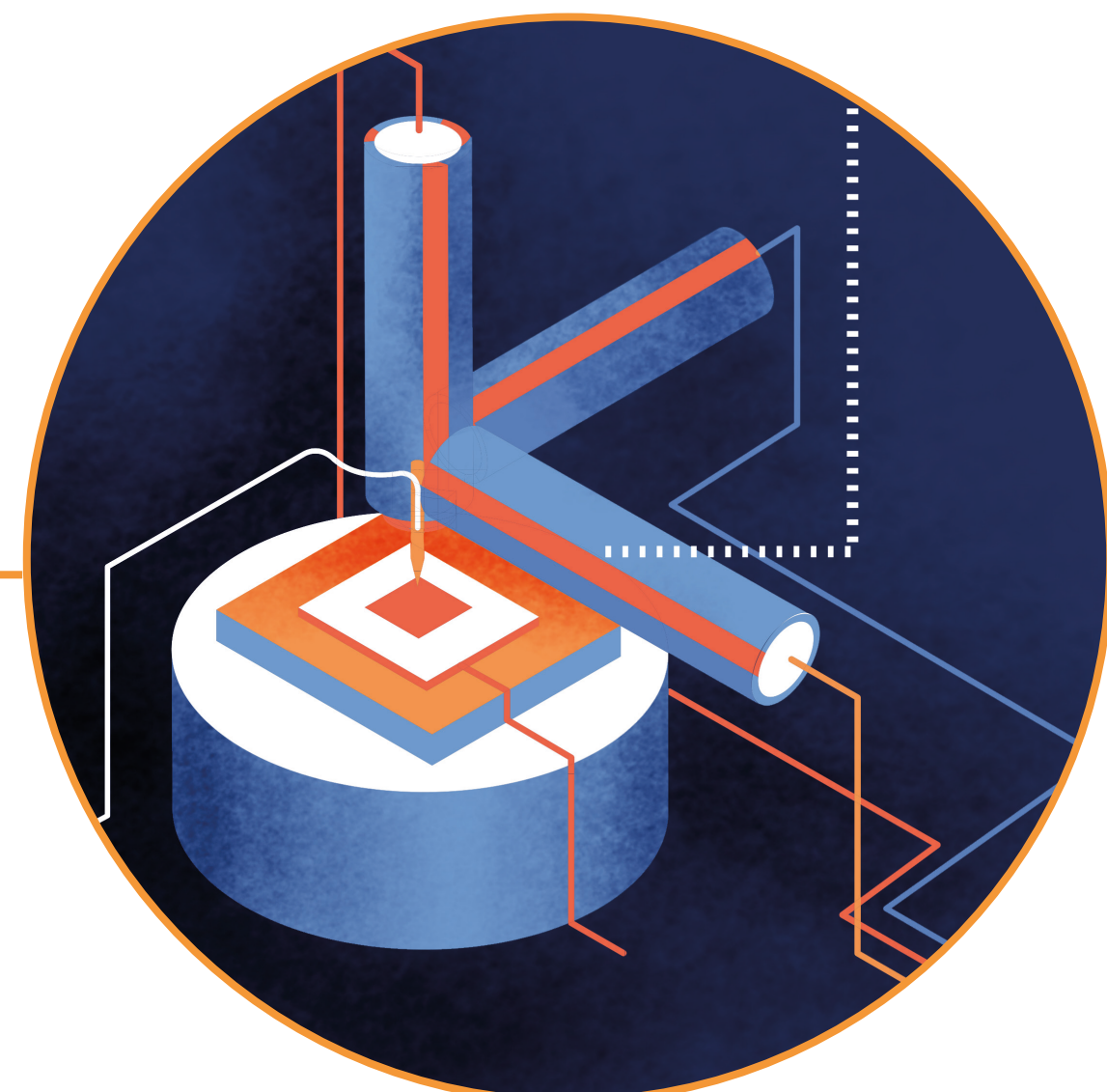


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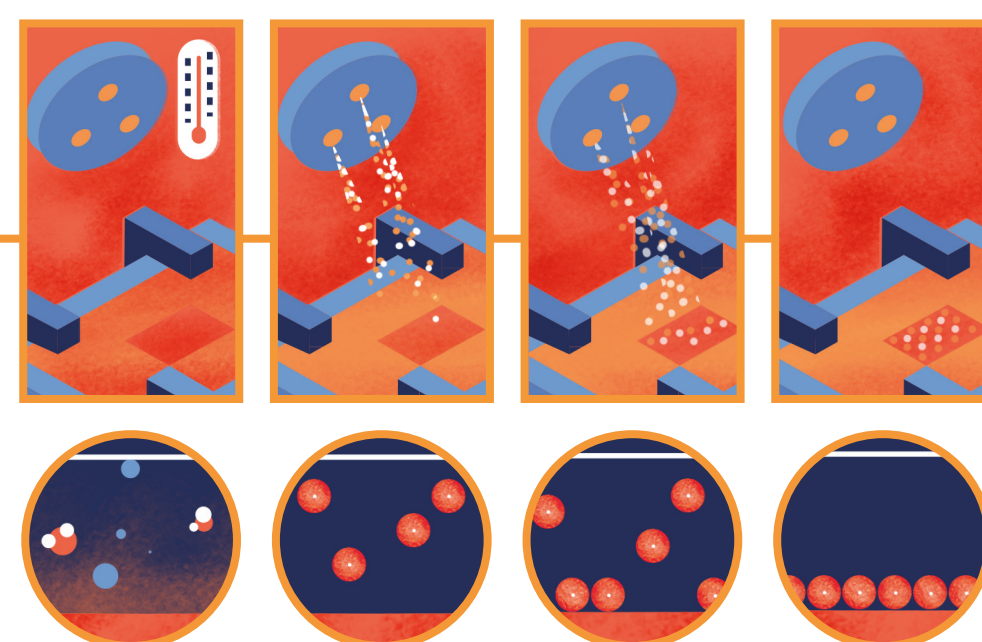
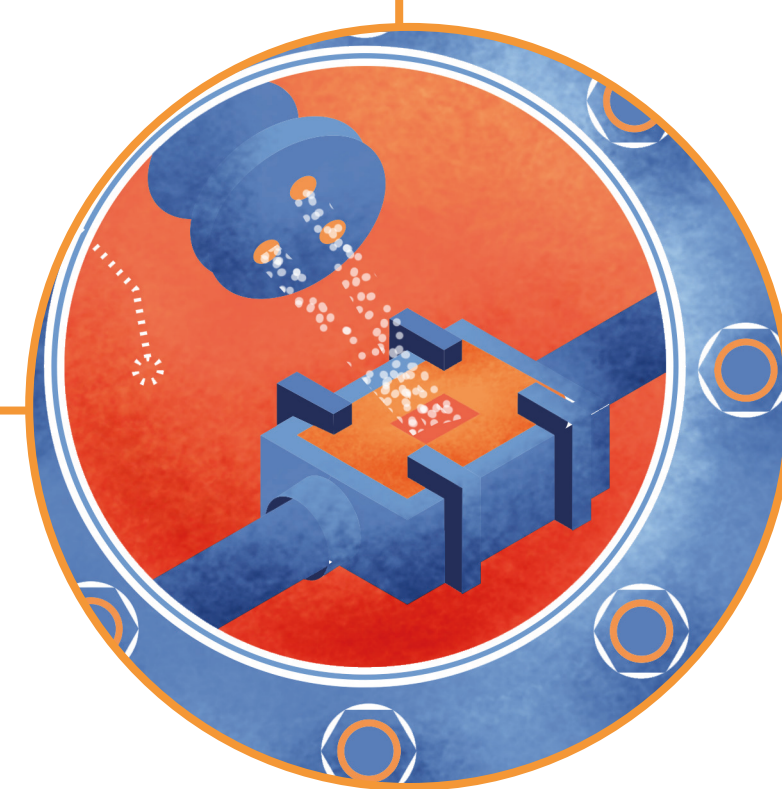
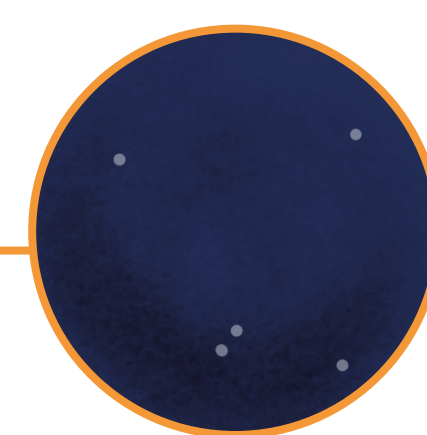
PIEZO ÉLECTRIQUE

sont les auteurs de l'article.
En 1986, ils sont récompensés
par Le Prix Nobel de physique
pour leur découverte.



PRÉPARATION DES ECHANTILLONS (AIR)

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over the surface at constant tunnel current as shown in Fig. 1. The displacements of the metal tip given by the voltages applied to the piezo-drives then yield a topographic picture of the surface. The very high resolution of the STM rests on the strong dependence of the tunnel current on the distance between the two tunnel electrodes, i.e., the metal tip and the scanned surface. The tunnel current through a planar tunnel barrier of average height ψ and width s is given by¹

$$J_T \propto \exp(-A\psi^{1/2}s), \quad (1)$$

where $A = (4\pi/\hbar)2m)^{1/2} = 1.025 \text{ \AA}^{-1} \text{ eV}^{-1/2}$, with m the free-electron mass, appropriate for a vacuum tunnel barrier. With barrier heights (work functions) of a few electronvolts, a change of the tunnel barrier width by a single atomic step ($\sim 2\text{--}5 \text{ \AA}$) changes the tunnel current up to three orders of magnitude. Using only the distance dependence as given by Eq. (1), and a spherical tip of radius R , one estimates a lateral spread δ of a surface step as $\delta = 3r_0 = 3(2R/A\psi^{1/2})^{1/2}$, i.e., $\delta(\text{\AA}) \approx 3[R(\text{\AA})]^{1/2}$. Thus, a lateral resolution considerably below 100 \AA requires tip radii of the order of 100 \AA . Such tips are standard in field-

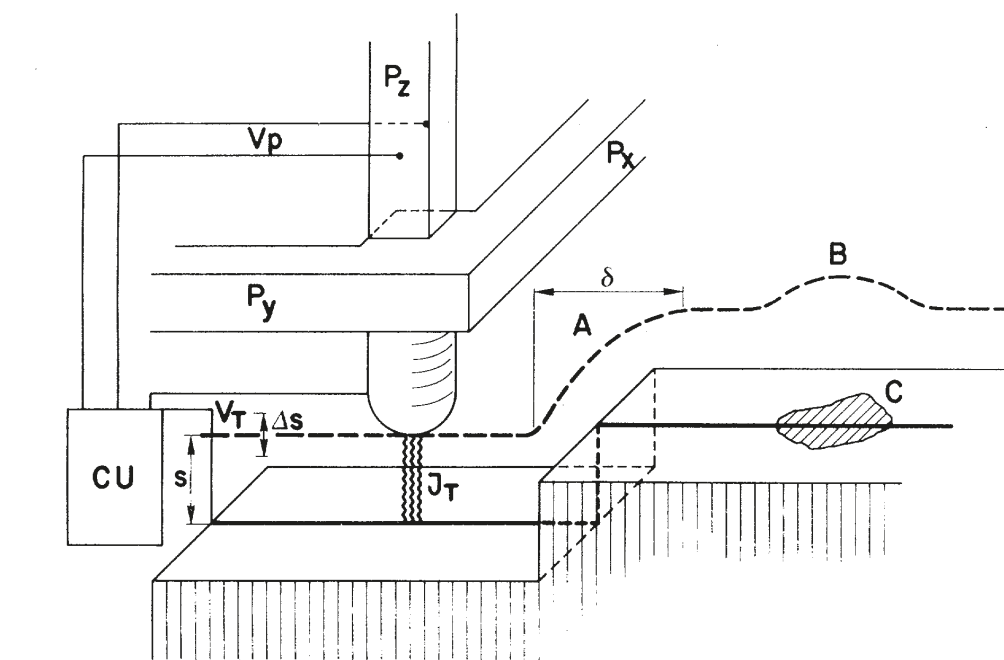


FIG. 1. Principle of operation of the scanning tunneling microscope. (Schematic: distances and sizes are not to scale.) The piezodrives P_x and P_y scan the metal tip M over the surface. The control unit (CU) applies the appropriate voltage V_p to the piezodrive P_x for constant tunnel current J_T at constant tunnel voltage V_T . For constant work function, the voltages applied to the piezodrives P_x , P_y , and P_z yield the topography of the surface directly, whereas modulation of the tunnel distance s by Δs gives a measure of the work function as explained in the text. The broken line indicates the z displacement in a y scan at (A) a surface step and (B) a contamination spot, C, with lower work function.

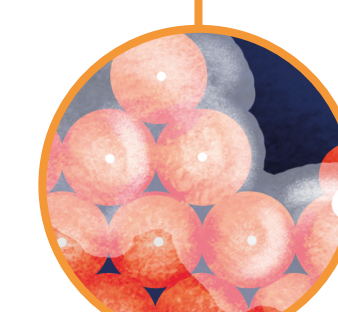
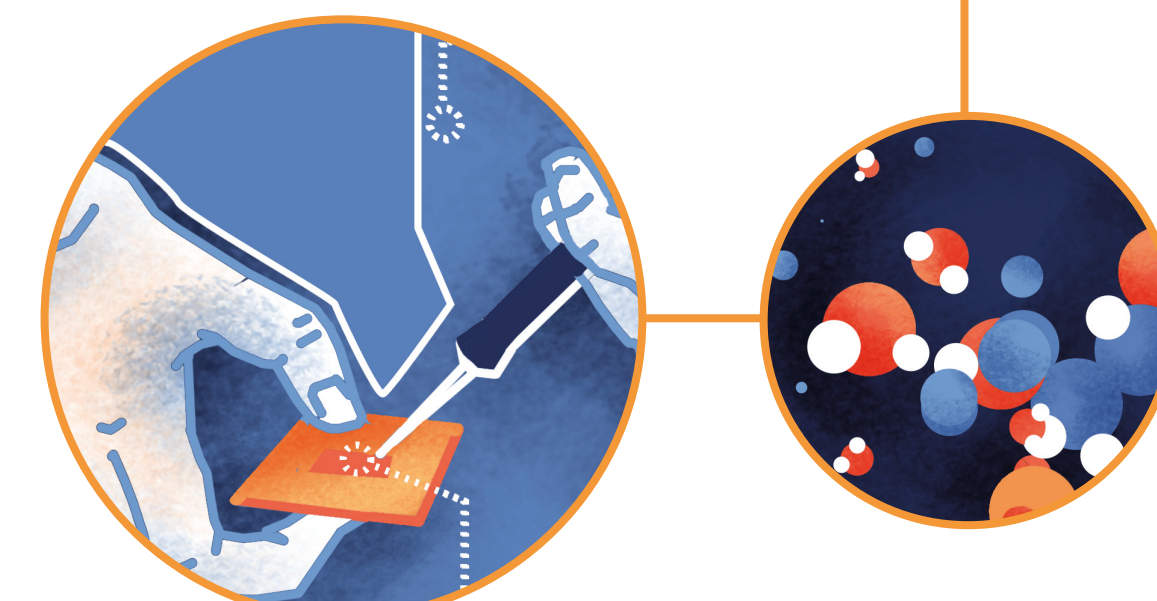
emission microscopy. However, since suppression of vibrations is evidently more vital for the STM, long and narrow field-emission tips might not be satisfactory. Instead, we used solid metal rods of 1 mm diameter, and ground 90° tips with a conventional grinding machine. This yielded overall tip radii of only some thousand angstroms to $1 \mu\text{m}$, but with some rather sharp minitips. The extreme sensitivity of the tunnel current on gap width then selects the longest of the minitips for operation of the STM. The lateral resolution could be increased further by gently touching the surface with the tip and subsequently retracting it. This "mini-spot-welding" procedure created very fine tips, such that monatomic steps could be resolved within 10 \AA laterally.

Scanning the tunnel tip at constant tunnel current implies $\psi^{1/2}s = \text{const}$. Thus, the z displacement of the tunnel tip gives the surface topography only for constant work function ψ , and therefore constant gap width s , as shown in Fig. 1 at A. On the other hand at B, the z displacement is caused by a change of work function on a structureless part of the surface. However, true surface structures and work-function-mimicked structures can be separated by modulating the gap width s while scanning, at a frequency higher than the cutoff frequency of the control unit. In a simple situation, as depicted in Fig. 1, the modulation signal gives the square root of the work function $\psi^{1/2} = \Delta(\ln J_T)/\Delta s$, directly, A in Eq. (1) being nearly 1. For general surface topographies, and work-function profiles, the separation process becomes rather involved. Then, the modulation Δs of the gap with s is no longer equal to the length modulation Δz of the piezodrive P_z . Essentially, $\Delta s = \Delta z \cos \phi$, where ϕ is the angle between the tunnel-surface element and the z direction. In turn, the modulation signal is no longer constant at true surface structures even for constant work function ψ . However, since V_p and the modulation signal contain ψ and s in a different way, their separation is, in principle, still possible even for involved structures and work-function profiles. In the following, we present topographic pictures of (110) surfaces of CaIrSn_4 and Au . Work-function profiles have not yet been studied in detail. They were used rather to get an overall picture of the surface condition.

CaIrSn₄.—The flux-grown single crystals exhibited shiny, natural faces after solving the remaining flux in HCl. Solvent etching probably stops at Ir layers, which appear to be rather

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inert.⁵ Therefore, they were good candidates for testing the operation of the STM at moderate vacuum ($\approx 10^{-6}$ Torr). Figure 2(a) shows a STM picture of a (110) surface obtained at room temperature without further surface treatment. We take the large flat parts (flat on an atomic scale) as an indication for a weak and homogeneous surface contamination. (No provision for simultaneous recording of work function and topography existed at the time of these experiments.) The pronounced structure on the left is the beginning of a growth spiral. Such spirals could be observed with both light and scanning electron microscopes. In the flat region, some monoatomic steps are clearly seen. Two scans with monoatomic, double-atomic, and triple-atomic steps are shown in Fig. 2(b). From all the steps observed, we obtained 6.7 Å as the average spacing of the Ir(110) planes. The piezodrives were calibrated by relacing the tip and sample with capacitor plates, giving a sensitivity of $2.0(\pm 0.2)$ Å/V in each direction. This step height agrees well with the 6.87 Å inferred from crystallographic data.⁶ Moreover, the form of the large steps is in qualitative agreement with that expected from simple calculations: a relatively sharp edge at the beginning of the step and considerable

smearing out at the end (as sketched in Fig. 1 at A).

Au.—The Au pictures were taken with a new, improved tunnel unit with considerably increased stability. The piezodrive material was calibrated in a conventional capacitance dilatometer within 2%, giving an accuracy of the sensitivity of the whole piezodrive of about 5%. The untreated (110) surface appeared structureless and mostly atomically flat. After Ar sputtering and subsequent annealing at 600 °C in $(2 \text{ to } 7) \times 10^{-10}$ Torr [a standard procedure for inducing reconstructions of Au (110) surfaces⁷⁻⁹], the surface appeared gently corrugated in the [001] direction as shown in Fig. 3(a). The work function was practically constant. The modulated signal showed variations of the order of a percent which reflect the surface corrugation rather than a true variation of the work function, as explained above. Repetition of the cleaning procedure led to qualitatively the same result. The corrugation is not strictly periodic; it varies from 20 to 100 Å in length and from some tenths to 2 Å in height, but with only small local variation in

MICROSCOPE À EFFET TUNNEL

c'est un très grand microscope qui permet d'observer la matière à l'échelle atomique et d'en comprendre les structures.

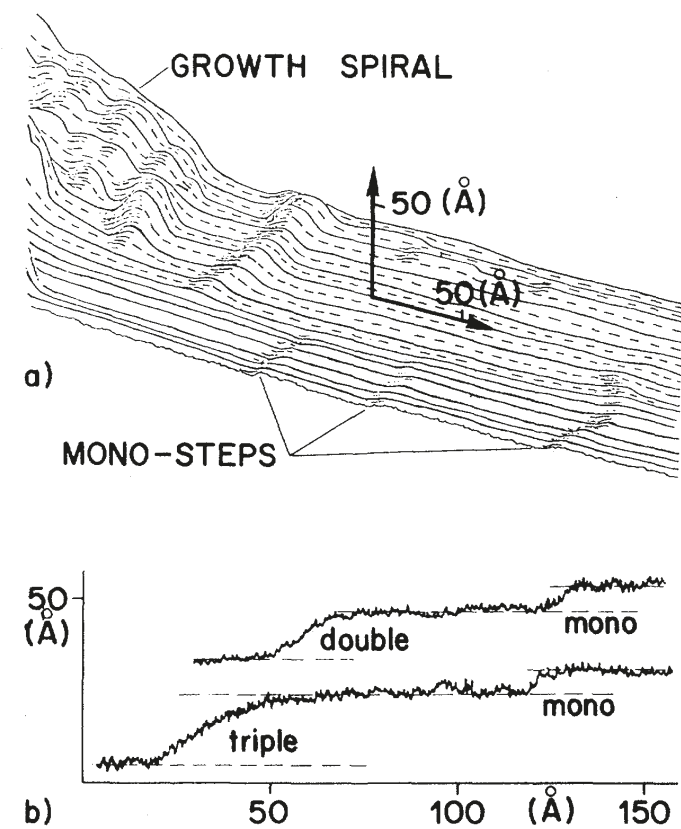
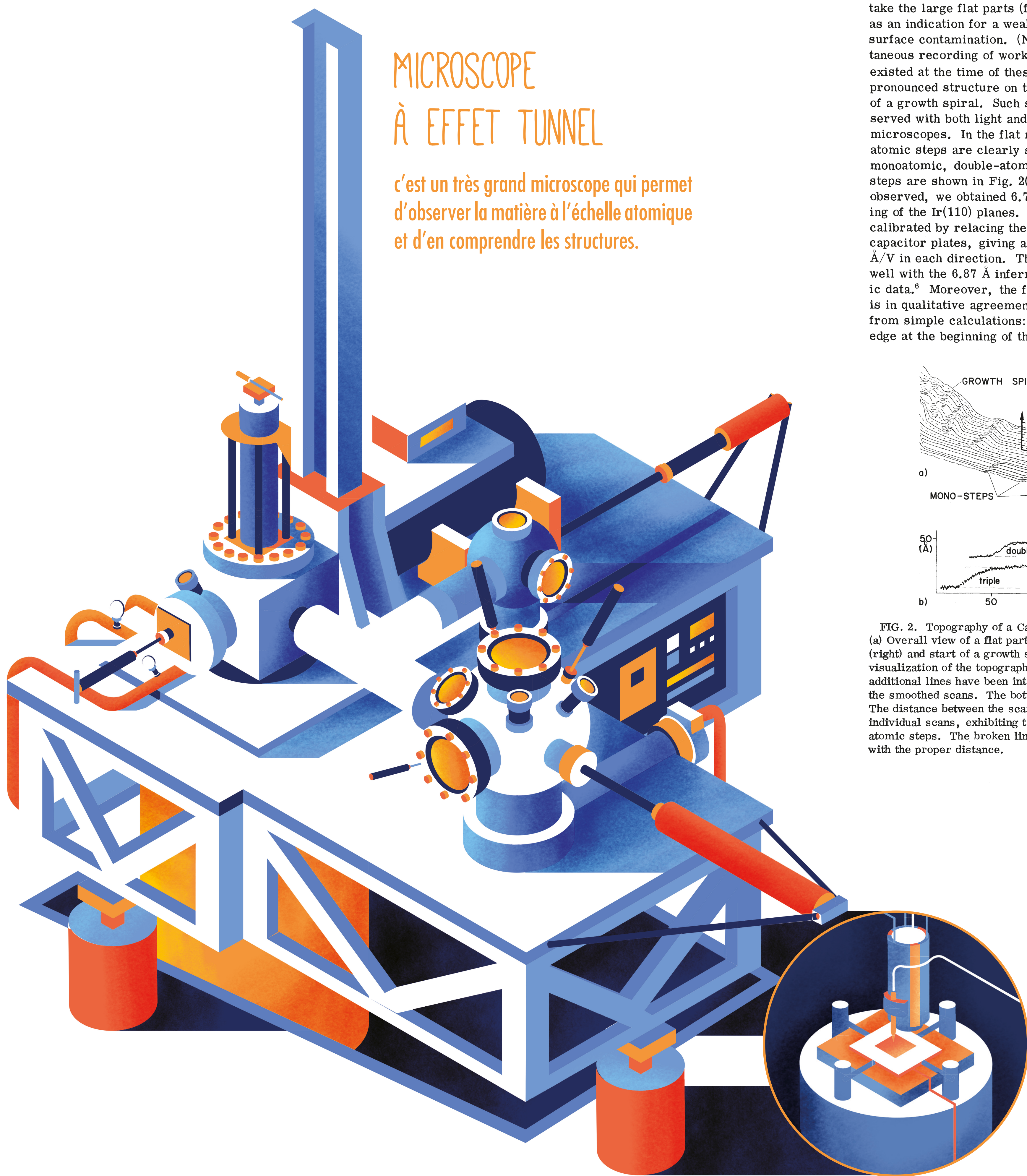


FIG. 2. Topography of a CaIrSn, (110) surface. (a) Overall view of a flat part with single atomic steps (right) and start of a growth spiral (left). For better visualization of the topography of the surface, some additional lines have been interpolated (broken) between the smoothed scans. The bottom line is as measured. The distance between the scans is uncalibrated. (b) Two individual scans, exhibiting triple, double, and mono-atomic steps. The broken lines indicate (110) faces, with the proper distance.

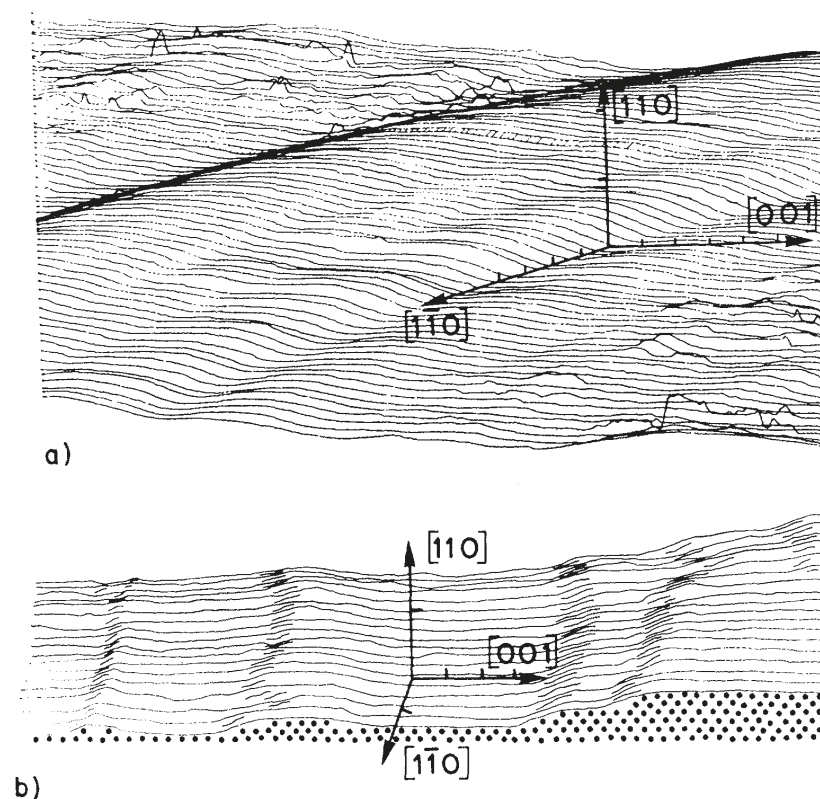
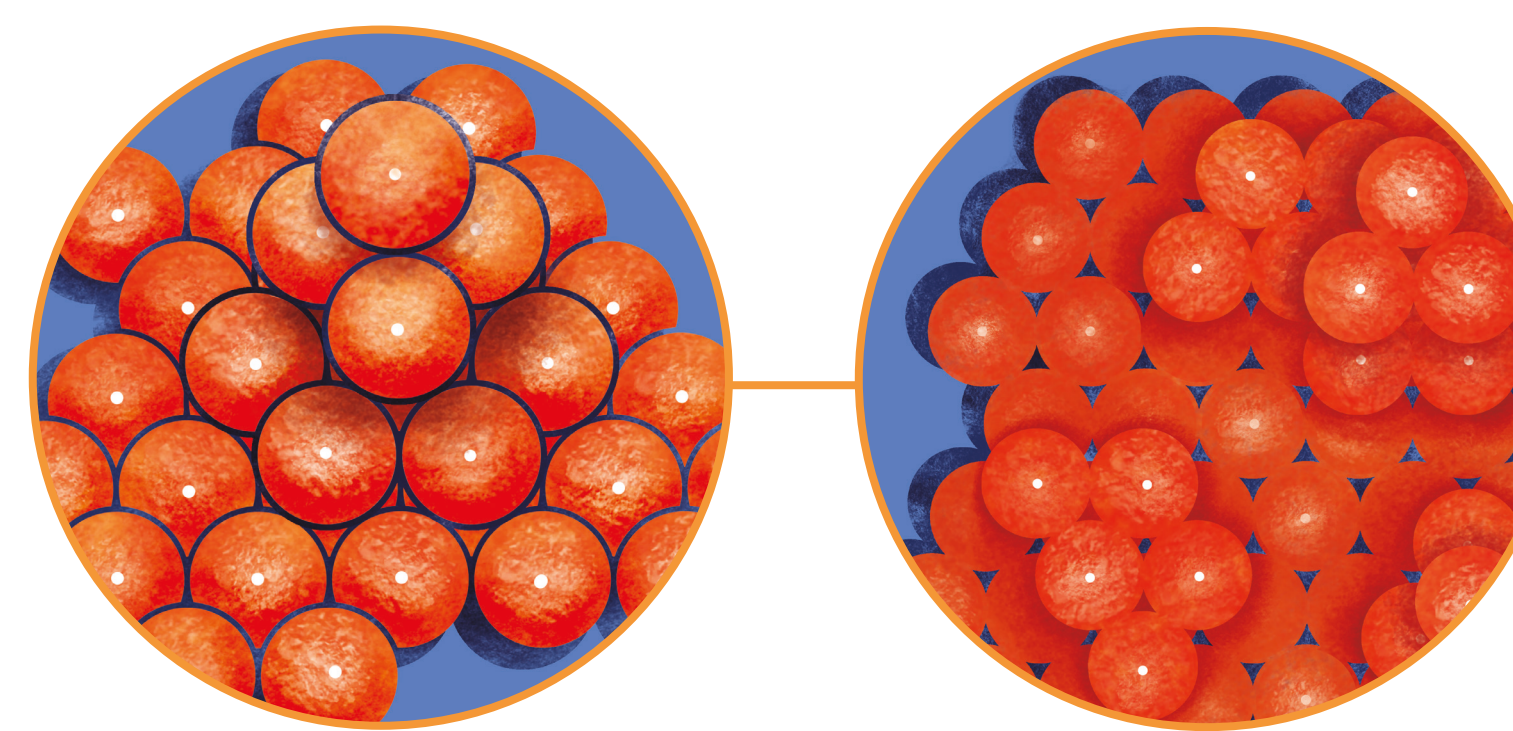


FIG. 3. Two examples of scanning tunneling micrographs of a Au (110) surface, taken at (a) room temperature, and (b) 300°C after annealing for 20 h at the same temperature (and essentially constant work function). The sensitivity is 10 Å/div everywhere. Because of a small thermal drift, there is some uncertainty in the crystal directions in the surface. In (a), the surface is gently corrugated in the [001] direction, except for a step of four atomic layers (≈ 2 atomic radii) along the [110] direction, as indicated by the discontinuity of the shaded ribbon. The steps in (b), which were always found along the [110] direction, are visualized by the possible positions of the Au atoms (dots).

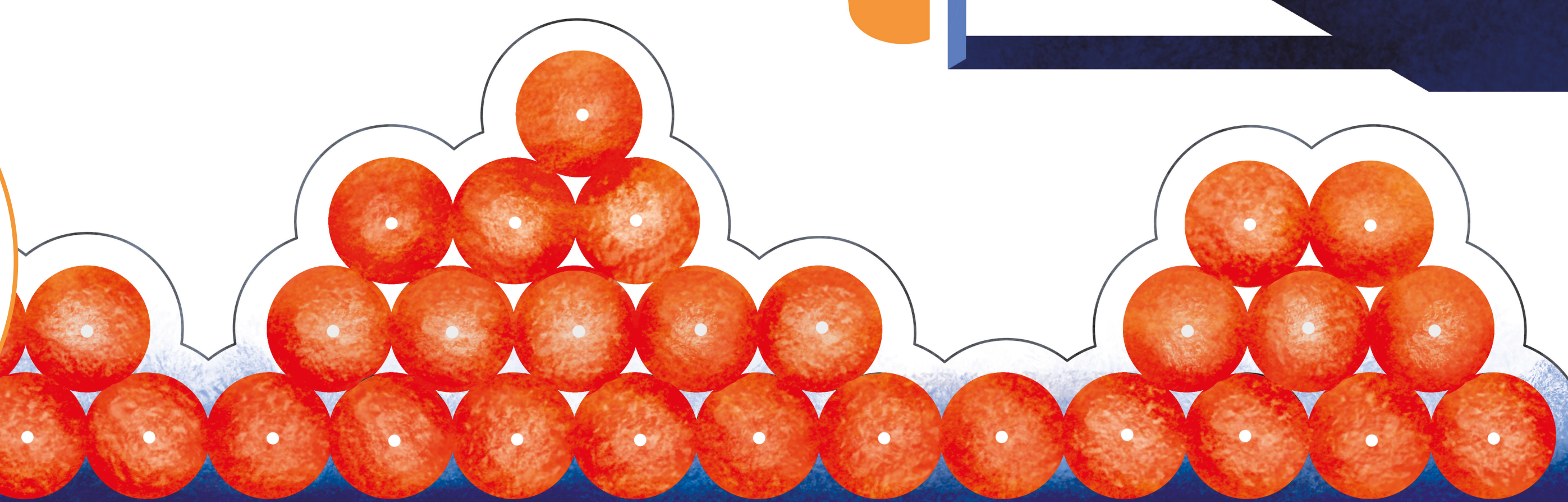


ESPACE DE CONTRÔLE DU MICROSCOPE À EFFET TUNNEL

Les scientifiques peuvent observer directement les échantillons sur un ordinateur. Ils dirige le microscope depuis des interfaces informatiques. Elles permettent de réguler entre-autre la température du cryostat pour maintenir les échantillons à une température avoisinant le zéro absolu.

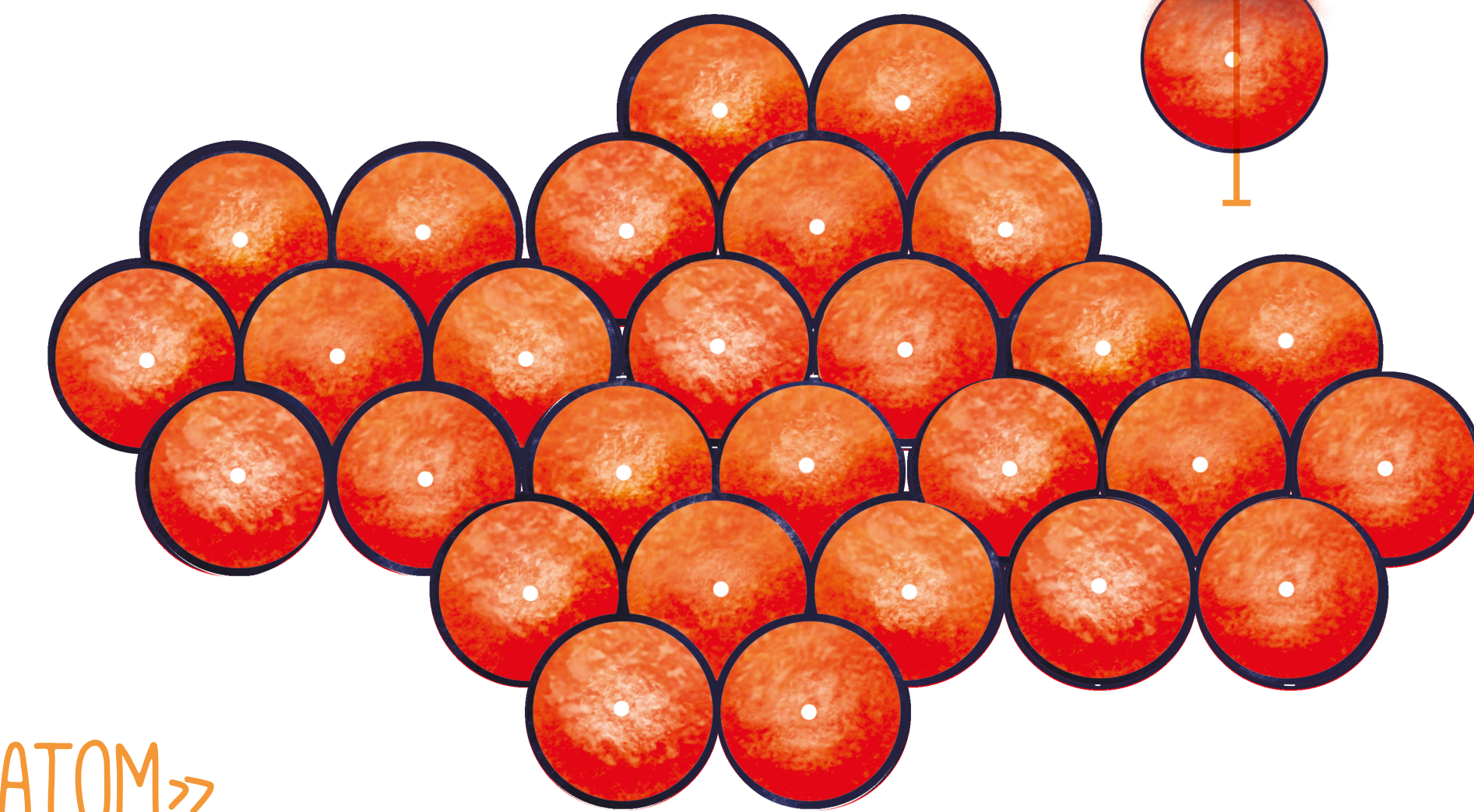
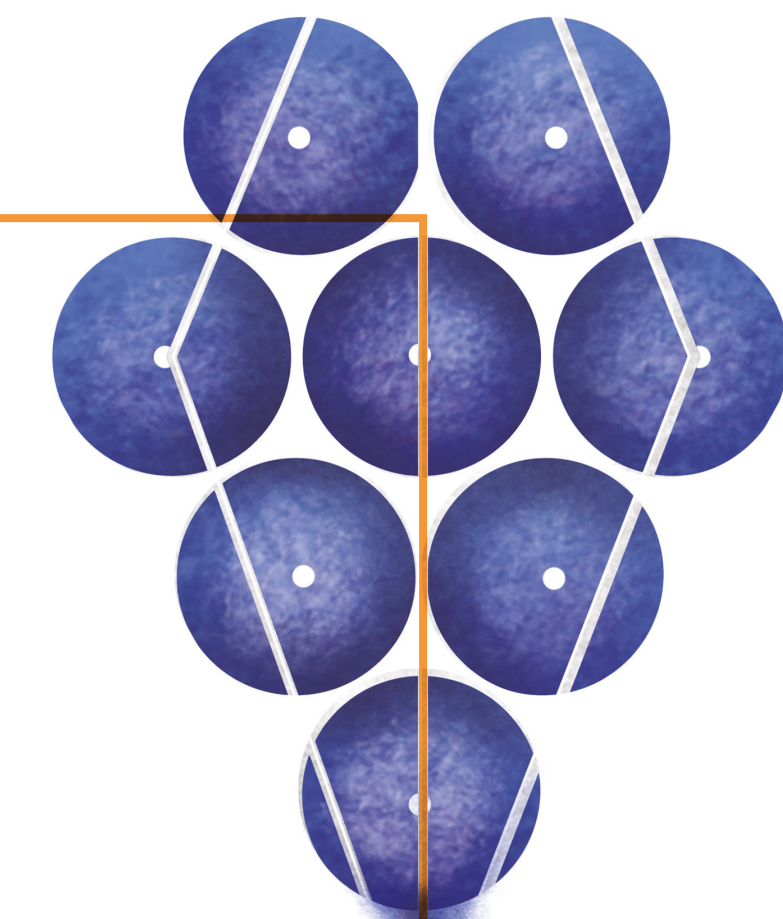


Ici on voit la mesure d'une surface d'or. On peut distinguer pour la première fois les différentes couches d'atomes. C'est la première fois dans l'histoire qu'on observe directement les atomes!



DÉPLACER LES ATOMES POUR CRÉER DE NOUVELLES STRUCTURES

En appliquant des tensions fortes à la pointe, on peut accrocher les atomes de la surface et les déplacer.



«A BOY
AND HIS ATOM»

Les chercheurs des laboratoires IBM créent le premier nanofilm de l'histoire. Tapez sur internet «A boy and his atom» pour voir la plus petite vidéo en stop motion du monde !!!



periodicity and height. A small corrugation of about 100 Å length in the [110] direction could be induced by rapidly cooling the sample to room temperature after annealing at 600 °C. Atomic steps could not usually be observed, and the step of 6 Å [equal to four (110) spacings or two atomic radii] shown in Fig. 3(a) is an exception. However, double or monoatomic steps were easily found at 300 °C [Fig. 3(b)]. An independent indication of an increasing step density with increasing temperature was recently obtained from an analysis of He-diffraction line shapes for Ni(100).¹⁰

Disorder along the [001] direction of Au(110) surfaces has been inferred from low-energy electron diffraction (LEED) experiments.⁸ The varying wavelength of the corrugation found in the present experiments induces such an anisotropic disorder. In view of the resolution demonstrated [see the steps in Fig. 3(b)], the corrugation is too smooth and flat to be explained in terms of some sequence of unrelaxed steps or a disordered 2×1 reconstruction of the missing-row type.⁶ It rather indicates a more continuous vertical displacement of the Au atoms. Surface buckling has been conjectured¹¹ for the Au(100) surface as a consequence of a mismatch of a topmost hexagonal layer with the underlying fcc structure. Reconstructions of the (110) surface are subject to quite some controversy. In particular, spin-polarized LEED experiments seem to rule out any of the proposed models containing a mirror plane perpendicular to the [110] chains or two-fold rotations.¹² The distorted hexagonal topmost layer model¹³ is compatible with the symmetry requirements of the spin-polarized LEED results. Although the present experiment did not reveal the double periodicity in the [100] direction, some distorted hexagonal topmost-layer structure appears to be an attractive explanation for the long-wave buckling. Even more, nonobservation of the 2×1 structure in the present experiment could be considered as support of this model. However, it is not certain whether a 2×1 reconstruction was indeed present, although it had been previously observed in the same crystal by TEAMS experiments.⁷ Combined LEED and tunnel experiments are planned to clear this point. Finally, it is interesting to note that the step in Fig. 3(a) separates a smooth portion of the surface (on the right) from an atomically rough one.

In summary, we have shown that scanning tunneling microscopy yields a true three-dimensional topography of surfaces on an atomic scale,

i.e., a resolution orders of magnitude better than scanning electron microscopy, with the possibility of extending it to work-function profiles (fourth dimension). The technique is nondestructive (energy of the tunnel "beam" 1 meV up to 4 eV), and uses fields down to three orders of magnitude less than field-ionization microscopy. The high current densities of 10⁸ to 10⁹ A/cm² appear to be no problem, and the technique has already been successfully extended to low-doped semiconductors.¹⁴ The significance of vacuum tunneling to surface studies and many other fields like space-resolved tunneling spectroscopy, microscopy of adsorbed molecules, and crystal growth, as well as for fundamental aspects of tunneling, especially in small geometries, is evident.

We thank R. Gambino and K. H. Rieder for providing the CaIrSn, and Au samples, respectively, H. R. Ott for calibrating the piezodriven material, B. Reihl and K. H. Rieder for discussions on surface aspects, and E. Courtens, K. A. Müller, and H. J. Scheel for their active interest in the STM.

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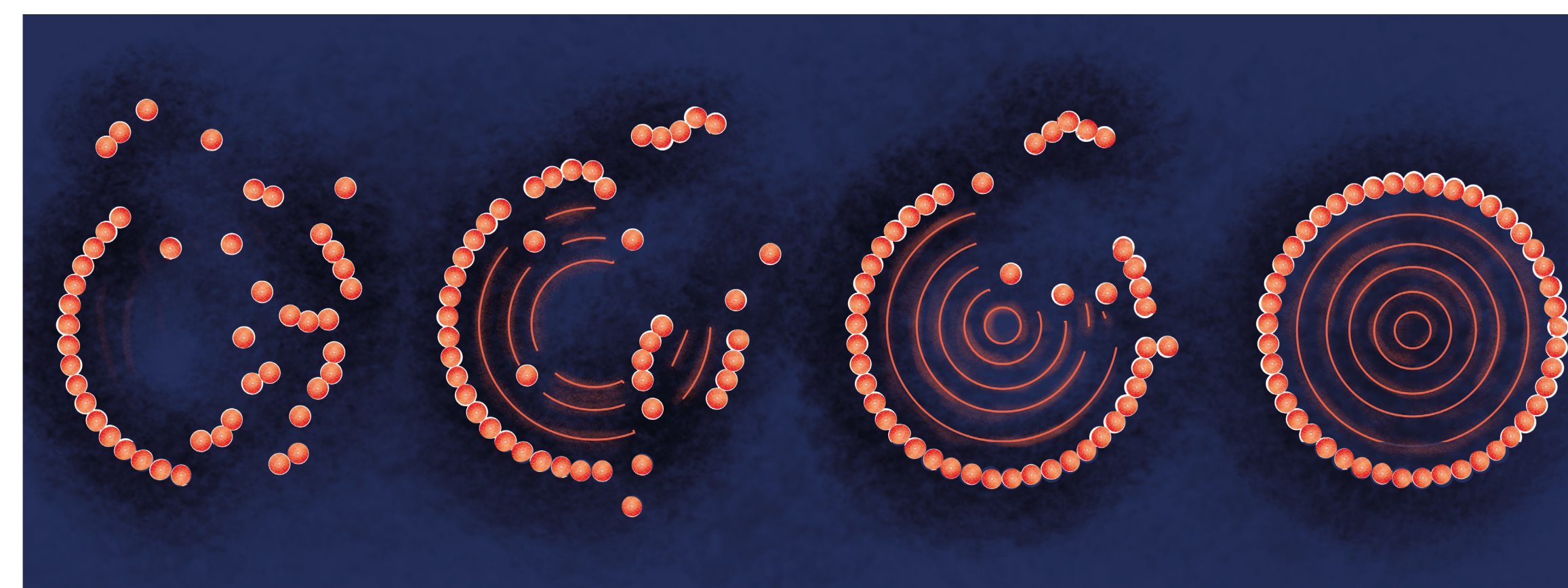
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¹²B. Reihl and B. I. Dunlap, *Appl. Phys. Lett.* **37**, 941 (1980).

¹³E. Lang, K. Heinz, and K. Müller, *Verh. Dtsch.*

On peut aussi construire des motifs atomiques. Ici, par exemple, une barrière d'atomes qui fait apparaître des ondes d'électrons.



LES NANOTECHNOLOGIES

Binnig et Rohrer comprennent que leur invention va permettre d'observer et de manipuler les atomes dans le futur...

Ce sera la naissance des nanosciences et des nanotechnologies !

